E ects of hydrogen adsorption on single wall carbon nanotubes: M etallic hydrogen decoration

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(Dated: March 22, 2024)

We show that the electronic and atom ic structure of carbon nanotubes undergo dram atic changes with hydrogen chem isorption from rst principle calculations. Upon uniform exohydrogenation at half coverage, the cross sections of zigzag nanotubes become literally square or rectangular, and they are metallic with very high density of states at the Ferm i level, while other isom ers can be insulating. For both zigzag and arm chair nanotubes, hydrogenation of each carbon atom from inside and outside alternatively yield the most stable isom er with a very weak curvature dependence and a large band gap.

PACS num bers: 73.22.-f, 68.43.Bc, 68.43.Fg, 68.43.-h

Single wall carbon nanotubes, 1,2 SW NTs, are among the most attractive systems for fabricating nanodevices because they exhibit m any unusualm echanical and electronic properties. Variation in the chiral vector or a sm all radial deformation result in marked changes ranging from insulating to idealone {dim ensional (1D) conducting properties.^{3,4,5,6,7} The physical and chem ical properties SW NTs can also be e ciently engineered by the adsorption of atom sorm olecules on nanotubes.^{8,9,10,11,12,13,14,15} Recently, it has been shown that the chemical activity of carbon nanotubes also depend on the chirality and radius,^{16,17} denoting tunable absorption of atom s on SW NTsby structural deform ation.^{17,18} The interplay between adsorption and electrom echanical properties can give rise to novel physiochem ical properties.^{17,18} The experim entally observed sensitivity of the electronic properties of SW NT s to the presence of oxygen and hydrogen is clear evidence for the importance of this interplay.¹⁹

M otivated by these considerations, we have investigated the structural and electronic properties of hydrogenated SW NTs (H-SW NT) as a function of hydrogen coverage and decoration (i.e. isom ers) by extensive rst principles calculations. Our results indicate that hydrogen adsorption on nanotubes gives rise to many novel properties which can mediate important applications in m olecular electronics. O ne of our m ost im portant results is that upon hydrogenation at uniform half coverage, the zigzag (n;0) SW NTs are metallized with high density of states at the Ferm i level and the circular cross sections of the tubes are changed to square or rectangle ones. The carbon atoms near the corners form new diamond{like C {C bonds. Therefore, these carbon atom s are electronically and chem ically passive, isolating the four conducting faces of the H-SW NT. Hence, loosely speaking a uniform half-coverage (n,0) H-SW NT is composed of fourwire nanocable.

O ur study com prises zigzag ((7;0), (8;0), (9;0), (10;0), (12;0)) and arm chair ((6;6), (10;10)) SW NTs which are hydrogenated at two di erent coverages. For full cover-

age (= 1), we consider two isomers; namely (i) exohydrogenation where each carbon atom is bonded to a hydrogen atom from outside of the nanotube (labeled by $C_{4n}H_{4n}$) and (ii) endo-exohydrogenation where each carbon atom is bonded to a hydrogen from inside and outside of the tube alternatively (labeled by $C_{4n}H_{2n}H_{2n}$). For half coverage (= 0.5), we consider the three most interesting isomers (labeled by $C_{4n}H_{2n}$); namely (i) uniform pattern where every other carbon atom is bonded to a hydrogen from outside, (ii) chain pattern where every other carbon zigzag chain is saturated by hydrogen, and (iii) dim er pattern where every other carbon dim er rows perpendicular to the zigzag carbon chains are saturated by hydrogen. Fig. 1a shows these three isomers at half coverage.

The rst principles total energy and electronic structure calculations have been carried out within the generalized gradient approximation $(G G A)^{21}$ using the pseudopotential plane wavem ethod²² in a supercell geom etry. D etails of the parameters used in this work are the same with those given in Ref.17. Fully relaxed geom etries are obtained by optimizing all atom ic positions and the lattice constant c along the tube-axis until the maximum force and stress are less than 0.01 eV/A and 0.1 GPa, respectively.

We nd that geometric and electronic structures and binding energies of H-SW NTs strongly depend on the pattern of hydrogenation (i.e. decoration). The most remarkable e ect is obtained when zigzag nanotubes are uniform by exohydrogenated at half-coverage (=0.5). Upon hydrogenation the structure undergoes a massive reconstruction, whereby circular cross section of the (7;0) SW NT changes to a rectangular one, and those of (8;0), (9;0), (10;0) and (12;0) change to square ones as shown in Fig. 1b. These new structures are stabilized by the form ation of new diam ond { like C {C bonds with d_{c c} 1.51-163 A near the commers of rectangular or square H-

SW NTs. Hence, triangular and pentagonal C rings are form ed instead of hexagonal. Depending on (2n m od 4),

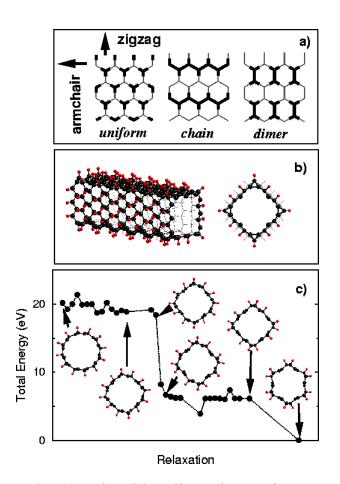


FIG.1: (a) A view of three di erent isom ers of H-SW NT at half coverage. The left and up arrows indicate the tube axis for arm chair and zigzag nanotubes, respectively. Carbon atom s which are bonded to hydrogens are indicated by dark color. (b) A side and top view of a (12;0) H-SW NT, indicating the square cross section of a uniform ly exohydrogenated nanotube at half coverage. (c) Several snap shots during the relaxation steps of an arm chair (6;6) H-SW NT, indicating that an uniform exohydrogenation at half coverage is not stable against form ing a chain isom er.

either one bond is form ed just at the corners or two bonds at either side of the corners. M ost interestingly, all these structures are found to be m etallic with a very large density of states at the Ferm i level. The uniform adsorption = 0.5 for zigzag nanotubes are metastable. Such a at local minimum does not exist for arm chair nanotubes, since uniform ly adsorbed H atom s are rearranged upon relaxation by concerted exchange of C {H bonds to form zigzag chains along the tube axis. Several snap shots for hydrogen dim erization on an arm chair tube are shown in Fig. 1c. The cross sections of chain isomerat = 0.5of arm chair tubes are polygonal where the corners are pinned by the zigzag H chains along the tube axis. For other isom ers at half-coverage as well as exo- and endoexohydrogenations at full coverage, the cross sections remain quasi-circular (see Fig. 2).

The average binding energies of H are obtained from

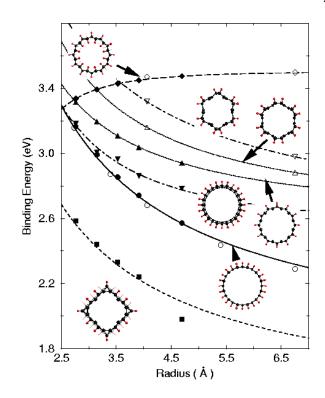


FIG.2: A verage binding energies, E_b , of hydrogen atoms adsorbed on various zigzag and arm chair SW NTs versus bare tube radius R. Filled and open symbols are for zigzag and arm chair nanotubes, respectively. C incles and diam onds are for exo- and endo-exohydrogenation at full coverage, respectively. The lled squares show the zigzag nanotubes uniform ly exohydrogenated at half coverage. The chain and dim er patterns of adsorbed hydrogen atoms at half coverage are show n by down- and up-triangles, respectively. C urves are analytical ts explained in the text. Insets show top view of several H-SW NT isom ers.

the expression,

$$E_{b} = (E_{T;C_{4n}} + m E_{H} E_{T;C_{4n}H_{m}}) = m$$
 (1)

in term s of the total energies of the bare SW NT, $E_{\rm T,C_{4n}}$, the hydrogen covered SW NT, $E_{\rm T,C_{4n}H_m}$, and the energy of atom ic hydrogen, $E_{\rm H}$ (m is the number of H atom s per unit cell). A coording to the above de nition stable structures have positive binding energies. The average binding energies as a function of nanotube radius are shown in Fig. 2. The variation of $E_{\rm b}$ with the radius of the bare nanotube can be tted to a simple form ula,^{16,17}

$$E_{b} = E_{o}() + \frac{C_{p}()}{R^{p}}$$
: (2)

Note that 1=R form (i.e. p=1) is quite common to SW NTs and scales various properties. 4,5,7,16,17 Here $E_{\rm o}($) is the binding energy when R $!\,$ 1 , and hence corresponds to the adsorption of H on graphene at a given coverage, while $C_{\rm p}($) is a constant that depends on coverage , and represents the curvature e ect. Calculated $E_{\rm b}{}'s$ are tted to Eq. 2 with the values listed

TABLE I:Values of the parameters $E_{\,0}$ (eV) and $C_{\,p}$ () (eV $A^{\,p})$ given in Eq.(2) to ~t the binding energies.

H ydrogen		Zigzag Tubes	Am chair Tubes
decoration	Εo	C _p ()	C _p ()
E xo = 1:0	1.75	C ₁ = 3 : 87	C ₁ = 3 : 87
E xo-endo = 1:0	3.51	C ₃ = 3:49	C ₃ = 3:49
Uniform = 0:5	1.41	C ₁ = 3:19	not stable
C hain = 0.5	2.50	C ₁ = 0:53	$C_1 = 3:16$
		$+ C_2 = 3:70$	$+ C_2 = 0:73$
D im er = 0:5	2.55	C ₁ = 1:41	$C_1 = 1:87$
		$+ C_2 = 1:94$	$+ C_2 = 2:42$

in Table I. W hile $E_{\rm b}$ increases with decreasing R in the case of exohydrogenation, this trend is reversed for endo-exohydrogenation due to increased H (H repulsion inside the tube at sm all R. N evertheless, the endo-exohydrogenation of SW NTs, which transforms the sp^2 to sp^3 -like bonding, gives rise to the highest binding energy saturating at 3.51 eV as R $!\,$ 1 . At this limit, the exo-endo hydrogenated graphene (from above and below) is buckled by 0.46 A as if two diam ond (111) planes with interplanar distance of 0.50 A .

As with the atom ic structure, the electronic structure of SW NTs undergo important changes as a result of hydrogenation. For bare zigzag SW NTs the variation of the band gap, E_g , with n is rather complex due to interplay between zone folding and curvature induced

m ixing^{7,20} while bare arm chair SW NT s arem etallic. Here we nd that sizable band gaps are opened as a result of hydrogenation (Fig. 3). At = 1, the band gap displays a sim ilar behavior for both type of nanotubes and hydrogenation, and decreases with inreasing R. Relatively larger band gaps (in the range of 3.5-4 eV) of endo-exohydrogenated SW NT s (=1) can be explained by the fact that the adsorption of H alternatively inside and outside leads to the atom ic con guration closer to the diam ond structure having rather large band gap (E_g = 5.4 eV).

The e ect of hydrogenation on the electronic structure is even m ore remarkable at = 0.5 and is the m ost interesting aspect of our study. Depending on the pattern of hydrogen adsorption, an isom er can be either a m etal or insulator. For example, all uniform (n,0) H-SW NTs are m etallic. On the other hand, the chain pattern realized on the (n;0) SW NTs results in two doubly degenerate, alm ost dispersionless states at the valence and conduction band edges. The band gap E_{q} between these states decreases with increasing R . W hen n is odd, E $_{\rm q}$ is large (e.g. $E_q = 2.1 \text{ eV}$ for (7;0)). When n is even the doubly degenerate band at the conduction band edge m oves towards the valence band edge and splits as bonding and anti-bonding states. As a result E_g is reduced signi cantly becoming only a pseudogap for large and even n. F inally, the dimer row isomers are insulators and the E_{q} increases with increasing radius. Surprisingly, there are

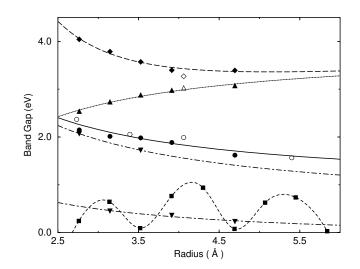


FIG.3: The band gaps, E_g, versus the bare nanotube radius R. Filled and empty symbols indicate zigzag and arm chair SW N T s, respectively. Squares show non-monotonic variation of the band gap of the bare zigzag nanotubes. Exo and endo-exohydrogenated nanotubes (=1) and chain and row patterns of adsorbed hydrogen atom s at half coverage are show n by circles, diamonds, down- and up-triangles, respectively. Lines are guide to eye.

two dispersive bands with 1 eV bandwidth at both band edges and extrem um moves from the center of Brillioun zone (-point) to the zone edge (Z-point).

Hydrogen adsorption induced dram atic changes of electronic structure are demonstrated by total density of states (DOS), D (E), of (9;0) nanotubes in Fig. 4. First of all, the sm all band gap of the bare (9;0) SW NT is opened by 2 eV upon exohydrogenation at = 1. The band gap is still signi cant for = 0.5 with the chain pattern, and increases to 4 eV for dim er pattern. However, a similar chain pattern in the (8;0) H-SW NT (see C₃₂H₁₆ in Fig. 4) has a much sm aller band gap. Suprisingly, all zigzag nanotubes uniform ly exohydrogenated at = 0.5 are m etals. As displayed in the sixth panel of Fig. 4 for $C_{36}H_{18}$ (uniform), their total density of states are characterized by a peak yielding high state density at E_F. W hile carbon states are pushed apart, yielding а 4-5 eV gap, a new dispersive m etallic band with 1-2 eV bandwidth crosses the Ferm i level. A part from being an ideal1D conductor, this very high density of states at EF might lead to superconductivity. Note that, these uniform H-SW NT sundergo a massive reconstruction and their circular cross sections change into square ones with the form ation of new C {C bonds (C4) at the corners. All C atom s without H attached (except those at corners) as well as the H atom s at the center of four planar sides contribute to the high D (E_F). This way four individual conduction paths are form ed on each side of square tube. It is emphasized that the transform ation from the sp^2 -to the sp³ bonding underlies various e ects discussed in this study. The H-SW NTs, especially C_{4n}H_{2n}H_{2n} structures

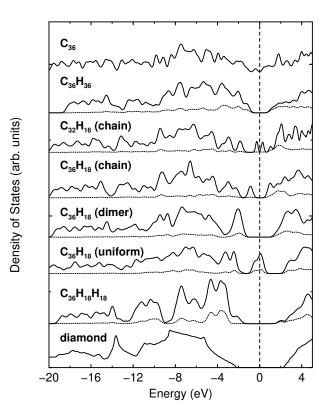


FIG.4: C om parison of the electronic density of states ($D \circ S$) of a bare (9;0) nanotube (C_{36}) and its various hydrogenated isom ers. $D \circ S$ of a chain pattern (8,0) H -SW NT at half coverage ($C_{32}H_{16}$) and bulk diam ond (bottom panel) are also shown for comparison. The zero of energy is taken at the Ferm ienergy showed by vertical dashed line. The dotted lines are the partial density of states resolved on hydrogen atom s.

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can be conceived as if they are more diam ond-like than graphitic. Our arguments are justimed by the comparison of D (E) of the endo-exohydrogenated (9;0) with that of bulk diam ond in Fig.4. A part from opening a large band gap, the quasimetallic D (E) of the bare (9;0) is modified to become similar to that bulk diam ond. The latter has relatively larger valence band width due to coupling of distant neighbors.

In conclusion, our study reveals many important and novel e ects of hydrogen adsorption on SW NTs, and brings a number of new problems and issues to be explored. For example, one can argue that the band gap of a SW NT can be engineered by the controlled hydrogenation of a single nanotube as in the alloy of $Si_x Ge_{1-x}$. A num ber of isom ers which can be tailored with di erent hydrogen decoration provide options in developing new materials. Furthermore, multiple quantum well structures, or one dimensional chain of quantum dots, can be tailored by periodic and modulated hydrogenation of a single nanotube. Finally, the very high density of states at the Ferm i level of uniform pattern isom er at half coverage may result in to superconductivity in SW NT based nanowires. Needless to say, realization of the systems proposed here will be an experim ental challenge. How ever, the fact that other carbon clusters such as cubane, dodecahedrane, and C₆₀H₃₂ have been successfully synthesized suggests that this is not in possible.

A cknow ledgm ents This work was partially supported by the NSF under Grant No. INT01-15021 and TUBITAK under Grant No. TBAG-U/13(101T010).

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